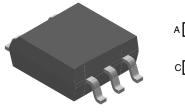
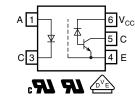
# VOM452, VOM453

Vishay Semiconductors



## Analog High Speed Coupler, High Noise Immunity, 1 MBd, SOP-5 Package





20409-1

## DESCRIPTION

The VOM452 and VOM453, high speed optocouplers, each consists of a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector and a high speed transistor. The photo detector is junction isolated from the transistor to reduce miller capacitance effects. The open collector output function allows circuit designers to adjust the load conditions when interfacing with different logic systems such as TTL, CMOS, etc.

Because the VOM452 and VOM453 have a Faraday shield on the detector chip, it can also reject and minimize high input to output common mode transient voltages. There is no base connection, further reducing the potential electrical noise entering the package.

The VOM452 and VOM453 are packaged in industry standard SOP-5 packages and are suitable for surface mounting.

This an ideal solution for Industrial communication bus isolation, as well as isolated drive circuit applications such as IPM (intelligent power module) drivers.

## FEATURES

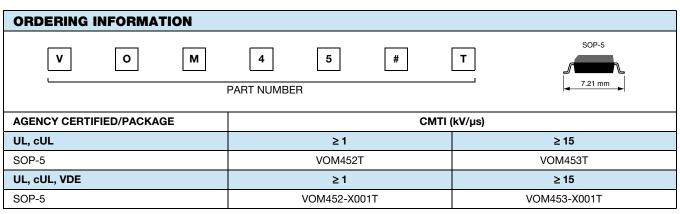
- Surface mountable
- Industry standard SOP-5 footprint
- Compatible with infrared vapor phase reflow and wave soldering processes
- Isolation test voltage, 3750 V<sub>RMS</sub>
- Very high common mode transient immunity: 15 000 V/µs at V<sub>CM</sub> = 1500 V guaranteed (VOM453)
- High speed: 1 MBd
- TTL compatible
- Open collector output
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## APPLICATIONS

- Fieldbus communication and control
- Logic ground isolation
- Analog signal ground isolation
- Replace pulse transformers
- IPM (intelligent power module) drivers

## AGENCY APPROVALS

- UL1577
- cUL
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1



#### Notes

• For additional information on the available options refer to option information.

• The product is available only on tape and reel.

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ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Reverse voltage		V <sub>R</sub>	3	V		
DC forward current		I <sub>F</sub>	25	mA		
Surge forward current	$t_p \le 1 \ \mu s$ , 300 pulses/s	I <sub>FSM</sub>	1	А		
Power dissipation	T <sub>amb</sub> ≤ 70 °C	P <sub>diss</sub>	45	mW		
OUTPUT						
Supply voltage		V <sub>S</sub>	-0.5 to +30	V		
Output voltage		Vo	-0.5 to +25	V		
Output current		Ι <sub>Ο</sub>	8	mA		
Power dissipation	T <sub>amb</sub> ≤ 70 °C	P <sub>diss</sub>	100	mW		
COUPLER						
Storage temperature range		T <sub>stg</sub>	-55 to +125	°C		
Ambient temperature range		T <sub>amb</sub>	-55 to +100	°C		
Junction temperature		Tj	100	°C		
Soldering temperature	t < 10 s max.		260	°C		

#### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = -40 °C to +100 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Input forward voltage	I <sub>F</sub> = 16 mA		V <sub>F</sub>	-	1.4	1.8	V
Input reverse current	V <sub>R</sub> = 3 V		I <sub>R</sub>	-	0.5	10	μA
Input capacitance	f = 1 MHz, $V_F$ = 0 V, $T_{amb}$ = 25 °C		C <sub>IN</sub>	-	75	-	pF
Temperature coefficient of forward voltage	I <sub>F</sub> = 16 mA		$\Delta V_F / \Delta T_{amb}$	-	-1.7	-	mV/°C
OUTPUT							
Logic low supply current	$I_F$ = 16 mA, $V_O$ = open, $V_{CC}$ = 15 V		I <sub>CCL</sub>	-	200	-	μA
Logic high supply current	$I_F = 0 \text{ mA}, V_O = \text{open}, V_{CC} = 15 \text{ V}, T_{amb} = 25 \text{ °C}$		I <sub>CCH</sub>	-	0.001	1	μA
	$I_F = 0$ mA, $V_O =$ open, $V_{CC} = 15$ V		I <sub>CCH</sub>	-	-	2	μA
Logic low output voltage	$I_{\rm F}$ = 16 mA, $V_{\rm CC}$ = 4.5 V, $I_{\rm O}$ = 3 mA, $T_{\rm amb}$ = 25 °C		V <sub>OL</sub>	-	0.15	0.4	V
	$I_F = 16 \text{ mA}, V_{CC} = 15 \text{ V}, I_O = 2.4 \text{ mA}$		V <sub>OL</sub>	-	-	0.5	V
	$I_F = 0$ mA, $V_O = V_{CC} = 5.5$ V, $T_{amb} = 25$ °C		I <sub>OH</sub>	-	0.003	0.5	μA
Logic high output current	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}, T_{amb} = 25 ^\circ\text{C}$		I <sub>OH</sub>	-	0.01	1	μA
	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}$		I <sub>OH</sub>	-	-	50	μA
COUPLER							
Capacitance (input-output) (1)	f = 1 MHz, T <sub>amb</sub> = 25 °C		C <sub>IO</sub>	-	0.4	-	pF

#### Notes

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements. All typical values are measured at T<sub>amb</sub> = 25 °C.

 $^{(1)}$  A 0.1  $\mu F$  bypass capacitor connected between pins 4 and 6 is recommended.

CURRENT TRANSFER RATIO (T <sub>amb</sub> = -40 °C to +100 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	TEST CONDITION SYMBOL MIN. TYP. MAX. UNIT					
Current transfer ratio (1)(2)	$V_{O}$ = 0.5 V, $I_{F}$ = 16 mA, $V_{CC}$ = 4.5 V	CTR 15 20	15	30	-	%	
	$V_{O}$ = 0.4 V, I <sub>F</sub> = 16 mA, T <sub>amb</sub> = 25 °C		20	-	50	70	

#### Notes

<sup>(1)</sup> Current transfer ratio in percent equals the ratio of output collector current (I<sub>Q</sub>) to the forward LED input current (I<sub>F</sub>) times 100. <sup>(2)</sup> A 0.1  $\mu$ F bypass capacitor connected between pins 4 and 6 is recommended. All typical values are measured at T<sub>amb</sub> = 25 °C.

Rev. 1.6, 31-May-16

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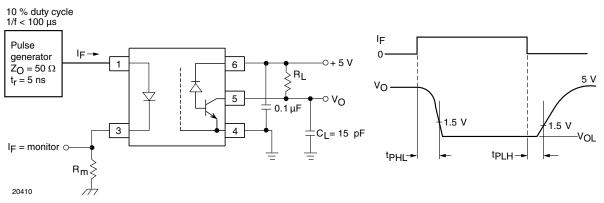
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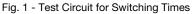
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SWITCHING CHARACTERISTICS (T <sub>amb</sub> = -40 °C to +100 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Propagation delay time to logic low at output (see fig. 1 and note 1)	$\begin{array}{l} V_{CC}=5~V,~I_{F}=16~mA,\\ R_{L}=1.9~k\Omega \end{array}$	t <sub>PHL</sub>	-	0.2	1	μs	
Propagation delay time to logic high at output (see fig. 1 and note 1)	$\label{eq:V_CC} \begin{array}{l} V_{CC} = 5 \; V, \; I_{F} = 16 \; mA, \\ R_{L} = 1.9 \; k\Omega \end{array}$	t <sub>PLH</sub>	-	0.5	1	μs	

Note

<sup>(1)</sup> The 1.9 k $\Omega$  load represents 1 TTL unit load of 1.6 mA and the 5.6 k $\Omega$  pull-up resistor. All typical values are measured at T<sub>amb</sub> = 25 °C.





<b>COMMON MODE TRANSIENT IMMUNITY</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Common mode transient immunity at logic high level output (see fig. 2 and notes 1, and 2)	$\label{eq:RL} \begin{split} R_L &= 1.9 \; k\Omega, \; I_F = 0 \; mA, \\ V_{CM} &= 10 \; V_{P\text{-}P} \end{split}$	VOM452T	CM <sub>H</sub>	1000	-	-	V/µs
		VOM453T	CM <sub>H</sub>	15 000	-	-	V/µs
Common mode transient immunity at logic low level output (see fig. 2 and notes 1, and 2)	$\label{eq:RL} \begin{split} R_L &= 1.9 \; k\Omega,  I_F = 16 \; mA, \\ V_{CM} &= 10 \; V_{P\text{-}P} \end{split}$	VOM452T	CML	1000	-	-	V/µs
		VOM453T	CM <sub>L</sub>	15 000	-	-	V/µs

#### Notes

- <sup>(1)</sup> Common mode transient immunity in a logic high level is the maximum tolerable (positive)  $dV_{CM}/dt$  on the leading edge of the common mode pulse ( $V_{CM}$ ) to assure that the output will remain in a logic high state (i.e.,  $V_0 > 2 V$ ). Common mode transient immunity in a logic low level the maximum tolerable (negative)  $dV_{CM}/dt$  on the trailing edge of the common mode pulse signal ( $V_{CM}$  to assure that the output will remain in logic low level to the trailing edge of the common mode pulse signal ( $V_{CM}$  to assure that the output will remain in logic low state, i.e.,  $V_0 > 0.8 V$ ).
- $^{(2)}$  The 1.9 k $\Omega$  load represents 1 TTL unit load of 1.6 mA and the 5.6 k $\Omega$  pull-up resistor.

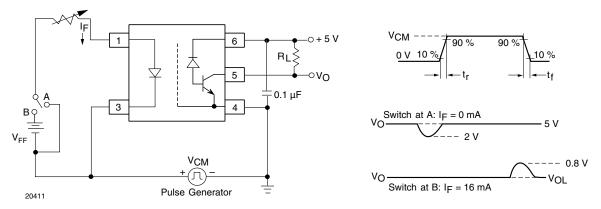


Fig. 2 - Test Circuit for Transient Immunity and Typical Waveforms

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PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V <sub>ISO</sub>	3750	V <sub>RMS</sub>
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V <sub>IOTM</sub>	6000	V <sub>peak</sub>
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	VIORM	707	V <sub>peak</sub>
Isolation resistance	$T_{amb} = 25 \ ^{\circ}C, \ V_{IO} = 500 \ V$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
	$T_{amb} = 100 \ ^{\circ}C, V_{IO} = 500 \ V$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Output safety power		P <sub>SO</sub>	350	mW
Input safety current		I <sub>SI</sub>	150	mA
Input safety temperature		Ts	175	°C
Creepage distance			≥5	mm
Clearance distance			≥5	mm
Insulation thickness		DTI	≥ 0.1	mm
Input to output test voltage, method B	$V_{IORM} \times 1.875 = V_{PR}$ , 100 % production test with $t_M = 1$ s, partial discharge < 5 pC	V <sub>PR</sub>	1669	V <sub>peak</sub>

#### Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

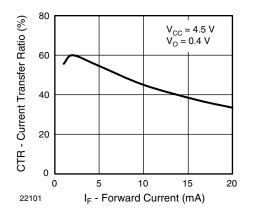


Fig. 3 - Current Transfer Ratio vs. Forward Current

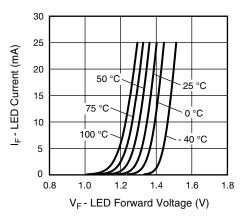


Fig. 4 - LED Current vs. LED Forward Voltage



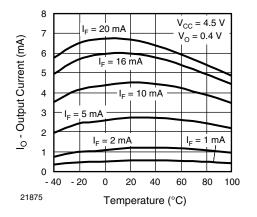


Fig. 5 - Output Current vs. Temperature

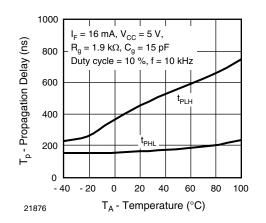


Fig. 6 - Propagation Delay vs. Temperature

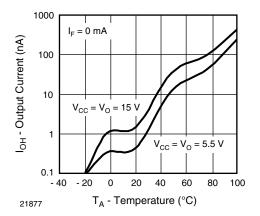
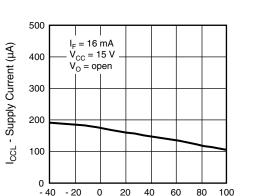


Fig. 7 - Logic High Output Current vs. Temperature



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Fig. 8 - Supply Current vs. Temperature

T<sub>A</sub> - Temperature (°C)

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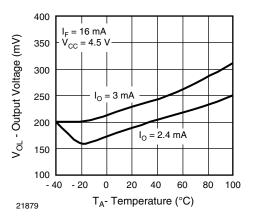


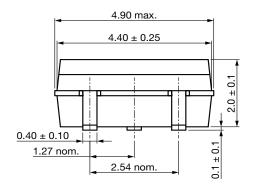
Fig. 9 - Logic Low Output Voltage vs. Temperature

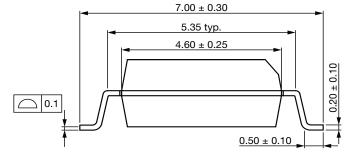
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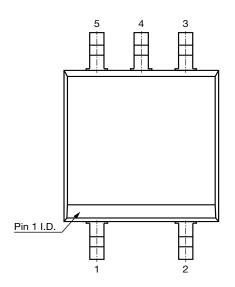


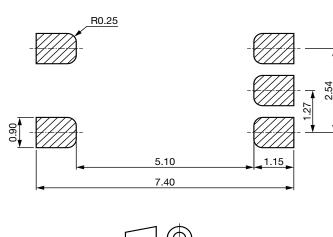
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### **PACKAGE MARKING**



Fig. 10 - Example of VOM452T

#### Notes

- VDE logo is not part of the package marking.
- Tape and reel suffix (T) is not part of the package marking.



Fig. 11 - Example of VOM452-X001T





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## **PACKING INFORMATION** (tape and reel)

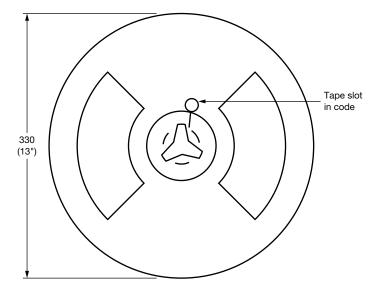


Fig. 12 - Tape and Reel Shipping Medium

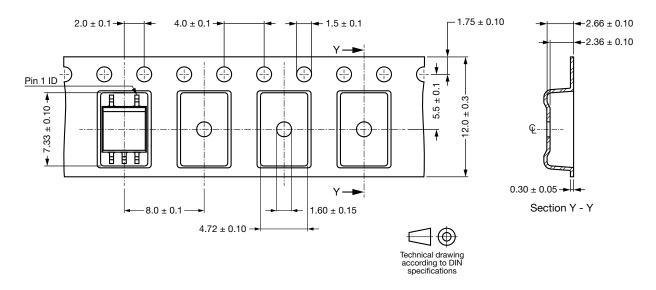


Fig. 13 - Tape and Reel Packing (2000 pieces on reel)



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### SOLDER PROFILE

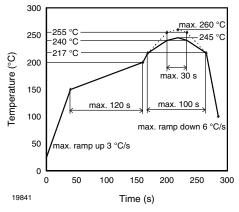


Fig. 14 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

## HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited Conditions:  $T_{amb} < 30$  °C, RH < 85 % Moisture sensitivity level 1, according to J-STD-020



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